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May 2017

FODM3011, FODM3012, FODM3023, FODM3052, FODM3053 4-Pin Full Pitch Mini-Flat Package Random-Phase Triac Driver Output Optocouplers

Features

- Compact 4-pin Surface Mount Package (2.4 mm Maximum Standoff Height)
- · Peak Blocking Voltage
 - 250V (FODM301X)
 - 400V (FODM302X)
 - 600V (FODM305X)
- Safety and Regulatory Approvals:
 - UL1577, 3,750 VAC_{RMS} for 1 Minute
 - DIN-EN/IEC60747-5-5, 565 V Peak Working Insulation Voltage

Applications

- · Industrial Controls
- Traffic Lights
- · Vending Machines
- Solid State Relay
- Lamp Ballasts
- · Solenoid/Valve Controls
- Static AC Power Switch
- Incandescent Lamp Dimmers
- Motor Control

Description

The FODM301X, FODM302X, and FODM305X series consists of a GaAs infrared emitting diode driving a silicon bilateral switch housed in a compact 4-pin miniflat package. The lead pitch is 2.54 mm. They are designed for interfacing between electronic controls and power triacs to control resistive and inductive loads for 115 V/240 V operations.

Functional Schematic

ANODE 1 CATHODE 2 AMAIN MAIN TERMINAL

Figure 1. Functional Schematic

Package Outlines

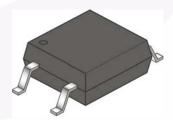


Figure 2. Package Outlines

Safety and Insulation Ratings

As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

Parameter		Characteristics
Installation Classifications per DIN VDE	< 150 V _{RMS}	I–IV
0110/1.89 Table 1, For Rated Mains Voltage	< 300 V _{RMS}	I–III
Climatic Classification		40/100/21
Pollution Degree (DIN VDE 0110/1.89)		2
Comparative Tracking Index		175

Symbol	Parameter	Value	Unit
V	Input-to-Output Test Voltage, Method A, $V_{IORM} \times 1.6 = V_{PR}$, Type and Sample Test with $t_m = 10 \text{ s}$, Partial Discharge < 5 pC	904	V _{peak}
V PR	Input-to-Output Test Voltage, Method B, V _{IORM} x 1.875 = V _{PR} , 100% Production Test with t _m = 1 s, Partial Discharge < 5 pC		V _{peak}
V _{IORM}	Maximum Working Insulation Voltage	565	V_{peak}
V_{IOTM}	Highest Allowable Over-Voltage	6000	V_{peak}
	External Creepage	≥ 5	mm
	External Clearance	≥ 5	mm
DTI	Distance Through Insulation (Insulation Thickness)	≥ 0.4	mm
T _S	Case Temperature ⁽¹⁾	150	°C
I _{S,INPUT}	Input Current ⁽¹⁾	200	mA
P _{S,OUTPUT}	Output Power ⁽¹⁾	300	mW
R _{IO}	Insulation Resistance at T _S , V _{IO} = 500 V ⁽¹⁾	> 10 ⁹	Ω

Note:

1. Safety limit values – maximum values allowed in the event of a failure.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. $T_A = 25^{\circ}C$ unless otherwise specified.

Symbol	Parameter		Value	Unit
T _{STG}	Storage Temperature		-55 to +150	°C
T _{OPR}	Operating Temperature		-40 to +100	°C
T _J	Junction Temperature		-40 to +125	°C
T _{SOL}	Lead Solder Temperature		260 for 10 sec	°C
EMITTER				
I _F (avg)	Continuous Forward Current		60	mA
I _F (pk)	Peak Forward Current (1 µs pulse, 300 pp	os.)	1	Α
V _R	Reverse Input Voltage		3	V
P _D	Power Dissipation (No derating required o	ver operating temp. range)	100	mW
DETECTOR				
I _{T(RMS)}	On-State RMS Current		70	mA (RMS)
		FODM3011, FODM3012	250	
V_{DRM}	Off-State Output Terminal Voltage	FODM3022, FODM3023	400	V
		FODM3052, FODM3053	600	
P_{D}	Power Dissipation (No derating required o	ver operating temp. range)	300	mW

Electrical Characteristics

 $T_A = 25$ °C unless otherwise specified.

Individual Component Characteristics

Symbol	Parameter	Test Conditions	Device	Min.	Тур.	Max.	Unit
EMITTER							
V _F	Input Forward Voltage	I _F = 10 mA	All		1.20	1.50	V
I _R	Reverse Leakage Current	$V_R = 3 \text{ V}, T_A = 25^{\circ}\text{C}$	All		0.01	100	μΑ
DETECTO	R						
I _{DRM}	Peak Blocking Current Either Direction	Rated V_{DRM} , $I_F = 0^{(2)}$	All		2	100	nA
dV/dt	Critical Rate of Rise of Off-State Voltage	I _F = 0 (Figure 8) ⁽³⁾	FODM3011, FODM3012, FODM3022, FODM3023		10		V/µs
			FODM3052, FODM3053	1,000			

Notes:

- 2. Test voltage must be applied within dv/dt rating.
- 3. This is static dv/dt. See Figure 1 for test circuit Commutating dv/dt is function of the load-driving thyristor(s) only.

Transfer Characteristics

Symbol	Parameter	Test Conditions	Device	Min.	Тур.	Max.	Unit
I _T LED Trigger Current	FO	FODM3011, FODM3022, FODM3052			10	mA	
I _T	TED Higger Current	Voltage = 3 V ⁽⁴⁾	FODM3012, FODM3023, FODM3053			5	IIIA
I _H	Holding Current, Either Direction		All		450		μΑ
V _{TM}	Peak On-State Voltage Either Direction	I _{TM} = 100 mA peak	All	A	2.2	3	V

Notes:

4. All devices are guaranteed to trigger at an I_F value of less than or equal to the max I_{FT} specification. For optimum operation over temperature and lifetime of the device, the LED should be biased with an I_F that is at least 50% higher than the maximum I_{FT} specification. The I_{FT} should not exceed the absolute maximum rating of 60 mA. Example: For FODM0353M, the minimum I_F bias should be 5 mA x 150% = 7.5 mA

Isolation Characteristics

Symbol	Parameter	Test Conditions	Device	Min.	Тур.	Max.	Unit
V _{ISO}	Steady State Isolation Voltage	1 Minute, R.H. = 40% to 60%	All	3,750			VAC _{RMS}

Typical Performance Characteristics

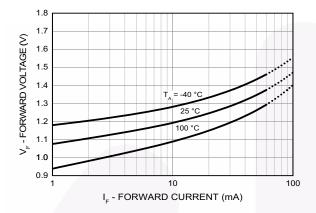
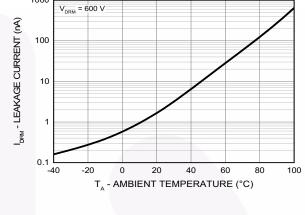


Fig 3. LED Forward Voltage vs. Forward Current



1000

Fig 4. Leakage Current vs. Ambient Temperature

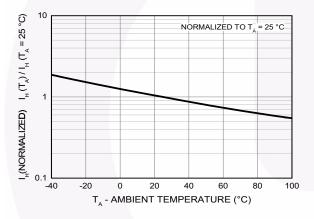


Fig 5. Normalized Holding Current vs. Ambient Temperature

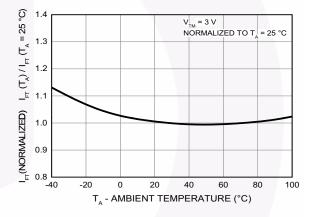
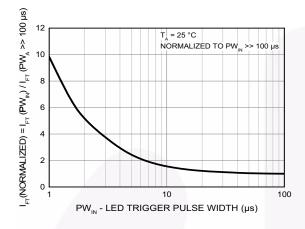


Fig 6. Normalized Trigger Current vs. Ambient Temperature

Typical Performance Characteristics (Continued)



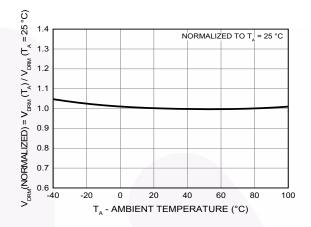


Fig 7. LED Current Required to Trigger vs. LED Pulse Width

Fig 8. Normalized Off-State Output Terminal Voltage vs. Ambient Temperature

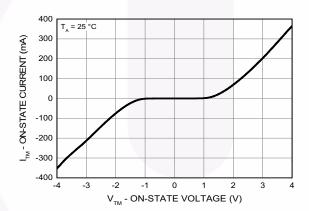
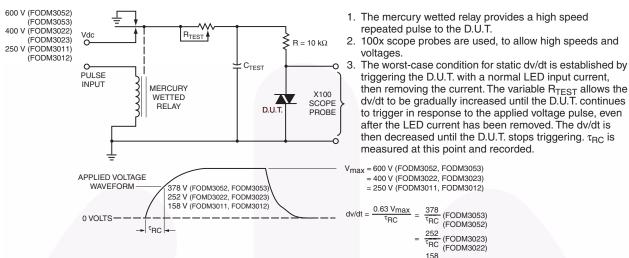


Fig 9. On-State Characteristics

Typical Application Information



- NOTE: This optoisolator should not be used to drive a load directly. It is intended to be a trigger device only.
- then decreased until the D.U.T. stops triggering. τ_{RC} is measured at this point and recorded.
 - = 400 V (FODM3022, FODM3023) = 250 V (FODM3011, FODM3012)
 - 378 τRC (FODM3053) (FODM3052) (FODM3023) (FODM3022)

(FODM3011)

(FODM3012)

Figure 10. Static dv/dt Test Circuit

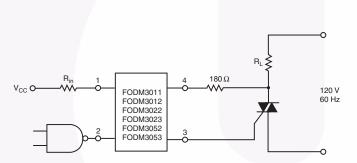


Figure 11. Resistive Load

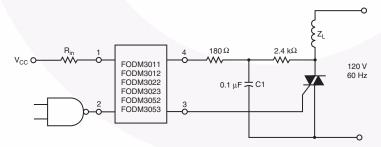
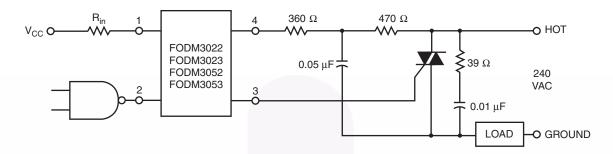


Figure 12. Inductive Load with Sensitive Gate Triac ($I_{GT} \le 15 \text{ mA}$)

Typical Application Information (Continued)

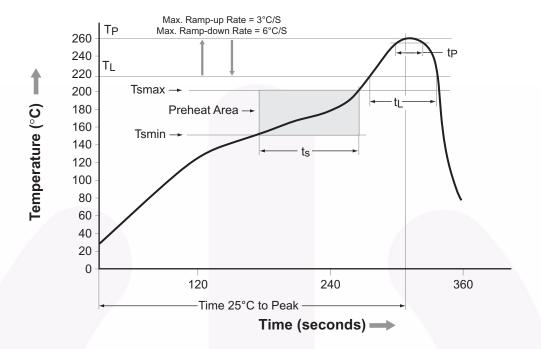


In this circuit the "hot" side of the line is switched and the load connected to the cold or ground side.

The 39 Ω resistor and 0.01 μ F capacitor are for snubbing of the triac, and the 470 Ω resistor and 0.05 μ F capacitor are for snubbing the coupler. These components may or may not be necessary depending upon the particular and load used.

Figure 13. Typical Application Circuit

Reflow Profile



Profile Freature	Pb-Free Assembly Profile		
Temperature Min. (Tsmin)	150°C		
Temperature Max. (Tsmax)	200°C		
Time (t _S) from (Tsmin to Tsmax)	60-120 seconds		
Ramp-up Rate (t _L to t _P)	3°C/second max.		
Liquidous Temperature (T _L)	217°C		
Time (t _L) Maintained Above (T _L)	60-150 seconds		
Peak Body Package Temperature	260°C +0°C / -5°C		
Time (t _P) within 5°C of 260°C	30 seconds		
Ramp-down Rate (T _P to T _L)	6°C/second max.		
Time 25°C to Peak Temperature	8 minutes max.		

Ordering Information

Part Number	Package	Packing Method
FODM3011	Full Pitch Mini-Flat 4-Pin	Tube (100 units)
FODM3011R2	Full Pitch Mini-Flat 4-Pin	Tape and Reel (2500 Units)
FODM3011V	Full Pitch Mini-Flat 4-Pin, DIN EN/IEC60747-5-5 Option	Tube (100 Units)
FODM3011R2V	Full Pitch Mini-Flat 4-Pin, DIN EN/IEC60747-5-5 Option	Tape and Reel (2500 Units)

Note:

The product orderable part number system listed in this table also applies to the FODM3012, FODM3022, FODM3023, FODM3052, and FODM3053 products.

Marking Information

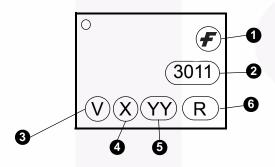
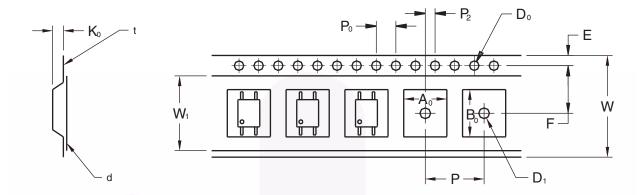


Figure 14. Top Mark

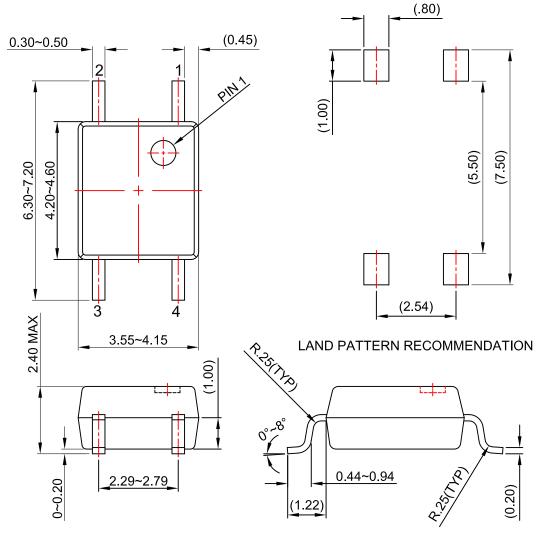
Table 1. Top Mark Definitions

1	Fairchild Logo
2	Device Number
3	DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option)
4	One-Digit Year Code, e.g., "6"
5	Digit Work Week, Ranging from "01" to "53"
6	Assembly Package Code

Tape Specifications



		2.54 Pitch
Description	Symbol	Dimensions
Tape Width	W	12.00±0.4
Tape Thickness	t	0.35±0.02
Sprocket Hole Pitch	P ₀	4.00±0.20
Sprocket Hole Dia.	D ₀	1.55±0.20
Sprocket Hole Location	E	1.75±0.20
Pocket Location	F	5.50±0.20
	P ₂	2.00±0.20
Pocket Pitch	Р	8.00±0.20
Pocket Dimension	A ₀	4.75±0.20
	B ₀	7.30±0.20
	K ₀	2.30±0.20
Pocket Hole Dia.	D ₁	1.55±0.20
Cover Tape Width	W ₁	9.20
Cover Tape Thickness	d	0.065±0.02
Max. Component Rotation or Tilt		20° max
Devices Per Reel		2500
Reel Diameter		330 mm (13")



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